INA190-Q1 AEC-Q100, 40-V, Bidirectional, Ultra-Precise Current Sense Amplifier With picoamp IB and ENABLE

1 Features

- AEC-Q100 qualified for automotive applications:
  - Temperature grade 1: –40°C to +125°C, T_A
- Functional Safety-Capable
  - Documentation available to aid functional safety system design
- Low input bias currents: 500 pA (typical) (enables microamp current measurement)
- Low power:
  - Low supply voltage, V_S: 1.7 V to 5.5 V
  - Low shutdown current: 100 nA (maximum)
  - Low quiescent current: 50 μA at 25°C (typical)
- Accuracy:
  - Common-mode rejection ratio: 132 dB (minimum)
  - Gain error: ±0.2% (A1 device)
  - Gain drift: 7 ppm/°C (maximum)
  - Offset voltage, V_OS: ±15 μV (maximum)
  - Offset drift: 80 nV/°C (maximum)
- Wide common-mode voltage: –0.2 V to +40 V with survivability up to 42 V
- Bidirectional current sensing capability
- Gain options:
  - INA190A1-Q1: 25 V/V
  - INA190A2-Q1: 50 V/V
  - INA190A3-Q1: 100 V/V
  - INA190A4-Q1: 200 V/V
  - INA190A5-Q1: 500 V/V

2 Applications

- Body control module (BCM)
- Telematics control unit
- Emergency call (eCall)
- Battery management system (BMS)
- Automotive head unit

3 Description

The INA190-Q1 is an automotive, low-power, voltage-output, current-shunt monitor (also called a current-sense amplifier). This device is commonly used for monitoring systems directly connected to an automotive 12-V battery. The INA190-Q1 can sense drops across shunts at common-mode voltages from –0.2 V to +40 V, independent of the supply voltage. In addition, the input pins have an absolute maximum voltage of 42 V.

The low input bias current of the device permits the use of larger current-sense resistors, thus providing accurate current measurements in the microamp range. The low offset voltage of the zero-drift architecture extends the dynamic range of the current measurement. This feature allows for smaller sense resistors with lower power loss, while still providing accurate current measurements.

The INA190-Q1 operates from a single 1.7-V to 5.5-V power supply, and draws a maximum of 65 μA of supply current when enabled; only 0.1 μA when disabled. Five fixed gain options are available: 25 V/V, 50 V/V, 100 V/V, 200 V/V, or 500 V/V. The device is specified over the operating temperature range of –40°C to +125°C, and offered in SC70 and SOT-23 packages.

![Typical Application Diagram](attachment:typical_application.png)

Typical Application

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An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.
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4 Revision History

Changes from Revision * (May 2019) to Revision A (March 2022)  Page

• Changed data sheet title from: INA190-Q1 Automotive, 40-V, High Precision, Low Bias Current, Low Power, Current Sense Amplifier to: INA190-Q1 AEC-Q100, 40-V, Bidirectional, Ultra-Precise Current Sense Amplifier With picocamp IB and ENABLE .................................................... 1
• Updated the numbering format for tables, figures, and cross-references throughout the document ........................................................ 1
• Added Functional Safety information to the Features section ........................................................ 1
• Added bullet to the Features section: Low shutdown current: 100 nA (maximum) ................................. 1
• Added bullet to the Features section: Common-mode rejection ratio: 132 dB (minimum) ....................... 1
• Changed the maximum gain drift in Features from: 5 ppm/°C to: 7 ppm/°C to match values in the Electrical Characteristics table ........................................................ 1
• Changed the maximum offset drift in Features from: 0.13 µV/°C to: 80 nV/°C to match values in the Electrical Characteristics table ........................................................ 1
• Changed the Applications section .................................................................................. 1
• Added DDF 8-pin SOT-23 package ............................................................................. 1
## 5 Pin Configuration and Functions

![Pin Configuration Diagram](image)

**Figure 5-1. DCK Package 6-Pin SC70 Top View**

<table>
<thead>
<tr>
<th>PIN</th>
<th>TYPE</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>VS</td>
<td>Analog</td>
<td>Power supply, 1.7 V to 5.5 V</td>
</tr>
<tr>
<td>GND</td>
<td>2</td>
<td>Digital input</td>
</tr>
<tr>
<td>IN–</td>
<td>5</td>
<td>Analog input</td>
</tr>
<tr>
<td>IN+</td>
<td>4</td>
<td>Analog input</td>
</tr>
<tr>
<td>NC</td>
<td>6</td>
<td>Not internally connected. Either float these pins or connect to any voltage between GND and VS.</td>
</tr>
<tr>
<td>OUT</td>
<td>6</td>
<td>Analog output</td>
</tr>
<tr>
<td>REF</td>
<td>1</td>
<td>Analog input</td>
</tr>
<tr>
<td>Vs</td>
<td>3</td>
<td>Analog input</td>
</tr>
</tbody>
</table>

**Table 5-1. Pin Functions**

<table>
<thead>
<tr>
<th>NAME</th>
<th>DCK</th>
<th>DDF</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>ENABLE</td>
<td>2</td>
<td></td>
<td>Digital input</td>
</tr>
<tr>
<td>GND</td>
<td>4</td>
<td></td>
<td>Analog Ground</td>
</tr>
<tr>
<td>IN–</td>
<td>8</td>
<td></td>
<td>Analog input crystuff amplifier negative input. For high-side applications, connect to load side of sense resistor. For low-side applications, connect to ground side of sense resistor.</td>
</tr>
<tr>
<td>IN+</td>
<td>7</td>
<td></td>
<td>Analog input current-source amplifier positive input. For high-side applications, connect to bus voltage side of sense resistor. For low-side applications, connect to load side of sense resistor.</td>
</tr>
<tr>
<td>NC</td>
<td>6</td>
<td></td>
<td>Not internally connected. Either float these pins or connect to any voltage between GND and VS.</td>
</tr>
<tr>
<td>OUT</td>
<td>5</td>
<td></td>
<td>Analog output OUT pin. This pin provides an analog voltage output that is the gained up voltage difference from the IN+ to the IN– pins, and is offset by the voltage applied to the REF pin.</td>
</tr>
<tr>
<td>REF</td>
<td>3</td>
<td></td>
<td>Analog input Reference input. Enables bidirectional current sensing with an externally applied voltage.</td>
</tr>
</tbody>
</table>

**Figure 5-2. DDF Package 8-Pin Thin SOT-23 Top View**
6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>MIN</th>
<th>NOM</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_S$</td>
<td>Supply voltage</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$V_{IN+}$, $V_{IN-}$</td>
<td>Analog inputs</td>
<td>Differential ($V_{IN+}$ – $V_{IN-}$)(2)</td>
<td>–42</td>
<td>42</td>
</tr>
<tr>
<td>$V_{IN+}$, $V_{IN-}$, with respect to GND(2)</td>
<td>GND – 0.3</td>
<td>42</td>
<td></td>
<td></td>
</tr>
<tr>
<td>$V_{ENABLE}$</td>
<td>ENABLE</td>
<td>GND – 0.3</td>
<td>6</td>
<td>V</td>
</tr>
<tr>
<td>REF, OUT(3)</td>
<td>Input current into any pin(3)</td>
<td>GND – 0.3</td>
<td>(V$S$) + 0.3</td>
<td>V</td>
</tr>
<tr>
<td>$T_A$</td>
<td>Operating temperature</td>
<td></td>
<td>–55</td>
<td>150</td>
</tr>
<tr>
<td>$T_J$</td>
<td>Junction temperature</td>
<td></td>
<td></td>
<td>150</td>
</tr>
<tr>
<td>$T_{stg}$</td>
<td>Storage temperature</td>
<td></td>
<td>–65</td>
<td>150</td>
</tr>
</tbody>
</table>

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) $V_{IN+}$ and $V_{IN-}$ are the voltages at the IN+ and IN– pins, respectively.

(3) Input voltage at any pin may exceed the voltage shown if the current at that pin is limited to 5 mA.

6.2 ESD Ratings

<table>
<thead>
<tr>
<th>Parameter</th>
<th>VALUE</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{(ESD)}$</td>
<td>Electrostatic discharge</td>
<td>Human-body model (HBM), per AEC Q100-002(1)</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Charged-device model (CDM), per AEC Q100-011</td>
</tr>
</tbody>
</table>

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>MIN</th>
<th>NOM</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{CM}$</td>
<td>Common-mode input range</td>
<td>GND – 0.2</td>
<td>40</td>
<td>V</td>
</tr>
<tr>
<td>$V_{IN+}$, $V_{IN-}$</td>
<td>Input pin voltage range</td>
<td>GND – 0.2</td>
<td>40</td>
<td>V</td>
</tr>
<tr>
<td>$V_S$</td>
<td>Operating supply voltage</td>
<td>1.7</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>$V_{REF}$</td>
<td>Reference pin voltage range</td>
<td>GND</td>
<td>$V_S$</td>
<td></td>
</tr>
<tr>
<td>$T_A$</td>
<td>Operating free-air temperature</td>
<td>–40</td>
<td>125</td>
<td>°C</td>
</tr>
</tbody>
</table>

6.4 Thermal Information

<table>
<thead>
<tr>
<th>THERMAL METRIC(1)</th>
<th>INA190-Q1</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>DCK (SC70)</td>
</tr>
<tr>
<td>$R_{qJA}$</td>
<td>Junction-to-ambient thermal resistance</td>
</tr>
<tr>
<td>$R_{qJC(top)}$</td>
<td>Junction-to-case (top) thermal resistance</td>
</tr>
<tr>
<td>$R_{qJB}$</td>
<td>Junction-to-board thermal resistance</td>
</tr>
<tr>
<td>$Y_{JT}$</td>
<td>Junction-to-top characterization parameter</td>
</tr>
<tr>
<td>$Y_{JB}$</td>
<td>Junction-to-board characterization parameter</td>
</tr>
<tr>
<td>$R_{qJC(bot)}$</td>
<td>Junction-to-case (bottom) thermal resistance</td>
</tr>
</tbody>
</table>

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.
## 6.5 Electrical Characteristics

at $T_A = 25^\circ\text{C}$, $V_{\text{SENSE}} = V_{\text{IN}+} - V_{\text{IN}–}$, $V_S = 1.8 \text{ V to } 5.0 \text{ V}$, $V_{\text{IN}+} = 12 \text{ V}$, $V_{\text{REF}} = V_S / 2$, and $V_{\text{ENABLE}} = V_S$ (unless otherwise noted)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>INPUT</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>CMRR</td>
<td>Common-mode rejection ratio</td>
<td>$V_{\text{SENSE}} = 0 \text{ mV}$, $V_{\text{IN}+} = -0.1 \text{ V to } 40 \text{ V}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$</td>
<td>132</td>
<td>150</td>
<td></td>
</tr>
<tr>
<td>$V_{\text{OS}}$</td>
<td>Offset voltage, RTI(1)</td>
<td>$V_S = 1.8 \text{ V}$, $V_{\text{SENSE}} = 0 \text{ mV}$</td>
<td>$-3$</td>
<td>±15</td>
<td>μV</td>
</tr>
<tr>
<td>$dV_{\text{OS}}/dT$</td>
<td>Offset drift, RTI</td>
<td>$V_{\text{SENSE}} = 0 \text{ mV}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$</td>
<td>10</td>
<td>80</td>
<td>nV/°C</td>
</tr>
<tr>
<td>PSRR</td>
<td>Power-supply rejection ratio, RTI</td>
<td>$V_{\text{SENSE}} = 0 \text{ mV}$, $V_S = 1.7 \text{ V to } 5.5 \text{ V}$</td>
<td>$-1$</td>
<td>±5</td>
<td>μV/V</td>
</tr>
<tr>
<td>$I_B$</td>
<td>Input bias current</td>
<td>$V_{\text{SENSE}} = 0 \text{ mV}$</td>
<td>0.5</td>
<td>3</td>
<td>nA</td>
</tr>
<tr>
<td>$I_O$</td>
<td>Input offset current</td>
<td>$V_{\text{SENSE}} = 0 \text{ mV}$</td>
<td>±0.07</td>
<td></td>
<td>nA</td>
</tr>
</tbody>
</table>

<table>
<thead>
<tr>
<th><strong>OUTPUT</strong></th>
<th></th>
<th>A1 devices</th>
<th>A2 devices</th>
<th>A3 devices</th>
<th>A4 devices</th>
<th>A5 devices</th>
</tr>
</thead>
<tbody>
<tr>
<td>$G$</td>
<td>Gain</td>
<td>25</td>
<td>50</td>
<td>100</td>
<td>200</td>
<td>500</td>
</tr>
<tr>
<td>$E_G$</td>
<td>Gain error</td>
<td>$V_{\text{OUT}} = 0.1 \text{ V to } V_S – 0.1 \text{ V}$</td>
<td>A1 devices</td>
<td>$-0.04%$</td>
<td>±0.2%</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>A2, A3, A4 devices</td>
<td>$-0.06%$</td>
<td>±0.3%</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>A5 devices</td>
<td>$-0.08%$</td>
<td>±0.4%</td>
<td></td>
</tr>
<tr>
<td>Gain error drift</td>
<td>$T_A = -40^\circ\text{C to } +125^\circ\text{C}$</td>
<td>2</td>
<td>7</td>
<td>ppm/°C</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Nonlinearity error</td>
<td>$V_{\text{OUT}} = 0.1 \text{ V to } V_S – 0.1 \text{ V}$</td>
<td>±0.01%</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$R_{\text{VRR}}$</td>
<td>Reference voltage rejection ratio</td>
<td>$V_{\text{REF}} = 100 \text{ mV to } V_S – 100 \text{ mV}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$</td>
<td>A1 devices</td>
<td>±2</td>
<td>±10</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>A2 devices</td>
<td>±1</td>
<td>±6</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>A3 devices</td>
<td>±0.5</td>
<td>±4</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>A4, A5 devices</td>
<td>±0.25</td>
<td>±3</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Maximum capacitive load</td>
<td>No sustained oscillation</td>
<td>1</td>
<td></td>
<td>nF</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

<table>
<thead>
<tr>
<th><strong>VOLTAGE OUTPUT</strong></th>
<th></th>
<th>A1, A2, A3 devices</th>
<th>A4 devices</th>
<th>A5 devices</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{\text{SP}}$</td>
<td>Swing to $V_S$ power-supply rail</td>
<td>$V_S = 1.8 \text{ V}$, $R_L = 10 \text{ kΩ to } \text{GND}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$</td>
<td>$(V_S) - 20$</td>
<td>$(V_S) - 40$</td>
</tr>
<tr>
<td>$V_{\text{SN}}$</td>
<td>Swing to GND</td>
<td>$V_S = 1.8 \text{ V}$, $R_L = 10 \text{ kΩ to } \text{GND}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$, $V_{\text{SENSE}} = -10 \text{ mV}$, $V_{\text{REF}} = 0 \text{ V}$</td>
<td>$(V_{\text{GND}}) + 0.05$</td>
<td>$(V_{\text{GND}}) + 1$</td>
</tr>
<tr>
<td>$V_{\text{SL}}$</td>
<td>Zero current output voltage</td>
<td>$V_S = 1.8 \text{ V}$, $R_L = 10 \text{ kΩ to } \text{GND}$, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$, $V_{\text{SENSE}} = 0 \text{ mV}$, $V_{\text{REF}} = 0 \text{ V}$</td>
<td>A1, A2, A3 devices</td>
<td>$(V_{\text{GND}}) + 1$</td>
</tr>
<tr>
<td></td>
<td></td>
<td>A4 devices</td>
<td>$(V_{\text{GND}}) + 2$</td>
<td>$(V_{\text{GND}}) + 4$</td>
</tr>
<tr>
<td></td>
<td></td>
<td>A5 devices</td>
<td>$(V_{\text{GND}}) + 3$</td>
<td>$(V_{\text{GND}}) + 9$</td>
</tr>
</tbody>
</table>

<table>
<thead>
<tr>
<th><strong>FREQUENCY RESPONSE</strong></th>
<th></th>
<th>A1 devices, $C_{\text{LOAD}} = 10 \text{ pF}$</th>
<th>A2 devices, $C_{\text{LOAD}} = 10 \text{ pF}$</th>
<th>A3 devices, $C_{\text{LOAD}} = 10 \text{ pF}$</th>
<th>A4 devices, $C_{\text{LOAD}} = 10 \text{ pF}$</th>
<th>A5 devices, $C_{\text{LOAD}} = 10 \text{ pF}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$B_W$</td>
<td>Bandwidth</td>
<td>45</td>
<td>37</td>
<td>35</td>
<td>33</td>
<td>27</td>
</tr>
<tr>
<td>$S_R$</td>
<td>Slew rate</td>
<td>$V_S = 5.0 \text{ V}$, $V_{\text{OUT}} = 0.5 \text{ V to } 4.5 \text{ V}$</td>
<td>0.3</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$T_S$</td>
<td>Settling time</td>
<td>From current step to within 1% of final value</td>
<td>30</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
at \( T_A = 25^\circ C \), \( V_{\text{SENSE}} = V_{\text{IN+}} - V_{\text{IN-}}, \) \( V_S = 1.8 \text{ V} \) to 5.0 \text{ V}, \( V_{\text{IN+}} = 12 \text{ V}, \) \( V_{\text{REF}} = V_S / 2, \) and \( V_{\text{ENABLE}} = V_S \) (unless otherwise noted)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>NOISE, RTI (1)</td>
<td>Voltage noise density</td>
<td>75</td>
<td>nV/\sqrt{Hz}</td>
<td></td>
<td></td>
</tr>
<tr>
<td>ENABLE</td>
<td>( I_{\text{EN}} ) Leakage input current</td>
<td>( 0 \text{ V} \leq V_{\text{ENABLE}} \leq V_S )</td>
<td>1</td>
<td>100</td>
<td>nA</td>
</tr>
<tr>
<td></td>
<td>( V_{\text{IH}} ) High-level input voltage</td>
<td>( 0.7 \times V_S )</td>
<td>6</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td>( V_{\text{IL}} ) Low-level input voltage</td>
<td>0</td>
<td>( 0.3 \times V_S )</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td>( V_{\text{HYS}} ) Hysteresis</td>
<td>300</td>
<td></td>
<td></td>
<td>mV</td>
</tr>
<tr>
<td></td>
<td>( I_{\text{DIS}} ) Output leakage disabled</td>
<td>( V_S = 5.0 \text{ V}, V_{\text{OUT}} = 0 \text{ V} ) to 5.0 \text{ V}, ( V_{\text{ENABLE}} = 0 \text{ V} )</td>
<td>1</td>
<td>5</td>
<td>( \mu A )</td>
</tr>
<tr>
<td>POWER SUPPLY</td>
<td>( I_Q ) Quiescent current</td>
<td>( V_S = 1.8 \text{ V}, V_{\text{SENSE}} = 0 \text{ mV} )</td>
<td>48</td>
<td>65</td>
<td>( \mu A )</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_S = 1.8 \text{ V}, V_{\text{SENSE}} = 0 \text{ mV}, T_A = -40^\circ \text{C} ) to 125(^\circ)C</td>
<td>90</td>
<td></td>
<td>( \mu A )</td>
</tr>
<tr>
<td></td>
<td>( I_{\text{QDIS}} ) Quiescent current disabled</td>
<td>( V_{\text{ENABLE}} = 0 \text{ V}, V_{\text{SENSE}} = 0 \text{ mV} )</td>
<td>10</td>
<td>100</td>
<td>nA</td>
</tr>
</tbody>
</table>

(1) RTI = referred-to-input.
6.6 Typical Characteristics

at \( T_A = 25^\circ C \), \( V_S = 1.8 \) V, \( V_{IN+} = 12 \) V, \( V_{REF} = V_S / 2 \), \( V_{ENABLE} = V_S(DDF) \), and for all gain options (unless otherwise noted)

Figure 6-1. Input Offset Voltage Production Distribution

Figure 6-2. Offset Voltage vs. Temperature

Figure 6-3. Common-Mode Rejection Production Distribution

Figure 6-4. Common-Mode Rejection Ratio vs. Temperature

Figure 6-5. Gain Error Production Distribution

Figure 6-6. Gain Error Production Distribution
6.6 Typical Characteristics (continued)

at \( T_A = 25^\circ C, V_S = 1.8 \text{ V}, V_{\text{IN+}} = 12 \text{ V}, V_{\text{REF}} = V_S / 2, V_{\text{ENABLE}} = V_S(\text{DDF}), \) and for all gain options (unless otherwise noted)
6.6 Typical Characteristics (continued)

at $T_A = 25°C$, $V_S = 1.8 V$, $V_{IN+} = 12 V$, $V_{REF} = V_S / 2$, $V_{ENABLE} = V_S$(DDF), and for all gain options (unless otherwise noted)
6.6 Typical Characteristics (continued)

at $T_A = 25^\circ C$, $V_S = 1.8$ V, $V_{IN+} = 12$ V, $V_{REF} = V_S / 2$, $V_{ENABLE} = V_S(DDF)$, and for all gain options (unless otherwise noted)

![Figure 6-19. Quiescent Current vs. Common Mode Voltage](image)

![Figure 6-20. Input-Referred Voltage Noise vs. Frequency](image)

![Figure 6-21. 0.1-Hz to 10-Hz Voltage Noise (Referred-To-Input)](image)

![Figure 6-22. Step Response (10-mVpp Input Step)](image)

![Figure 6-23. Common-Mode Voltage Transient Response](image)

![Figure 6-24. Inverting Differential Input Overload](image)
6.6 Typical Characteristics (continued)

at \( T_A = 25^\circ C, V_S = 1.8 \text{ V}, V_{\text{IN}+} = 12 \text{ V}, V_{\text{REF}} = V_S / 2, V_{\text{ENABLE}} = V_S(\text{DDF}), \) and for all gain options (unless otherwise noted)

**Figure 6-25. Noninverting Differential Input Overload**

**Figure 6-26. Start-Up Response**

**Figure 6-27. Brownout Recovery**

**Figure 6-28. Enable and Disable Response**

**Figure 6-29. IB+ and IB– vs. Differential Input Voltage**

**Figure 6-30. IB+ and IB– vs. Differential Input Voltage**
6.6 Typical Characteristics (continued)

at $T_A = 25^\circ C$, $V_S = 1.8$ V, $V_{IN+} = 12$ V, $V_{REF} = V_S / 2$, $V_{ENABLE} = V_S(DDF)$, and for all gain options (unless otherwise noted)

![Graph showing output leakage vs. output voltage for A1, A2, and A3 devices.](image1)

$V_S = 5.0$ V, $V_{ENABLE} = 0$ V, $V_{REF} = 2.5$ V

Figure 6-31. Output Leakage vs. Output Voltage (A1, A2, and A3 Devices)

![Graph showing output leakage vs. output voltage for A4 and A5 devices.](image2)

$V_S = 5.0$ V, $V_{ENABLE} = 0$ V, $V_{REF} = 2.5$ V

Figure 6-32. Output Leakage vs. Output Voltage (A4 and A5 Devices)

![Graph showing output impedance vs. frequency.](image3)

$V_S = 5.0$ V, $V_{CM} = 0$ V

Figure 6-33. Output Impedance vs. Frequency
7 Detailed Description

7.1 Overview

The INA190-Q1 is a low bias current, low offset, 40-V common-mode, current-sensing amplifier. The DDF SOT-23 package also features an enable pin. The INA190-Q1 is a specially designed, current-sensing amplifier that accurately measures voltages developed across current-sensing resistors on common-mode voltages that far exceed the supply voltage. Current is measured on input voltage rails as high as 40 V at \( V_{IN+} \) and \( V_{IN–} \), with a supply voltage, \( V_S \), as low as 1.7 V. When disabled, the output goes to a high-impedance state, and the supply current draw is reduced to less than 0.1 µA. The INA190-Q1 is intended for use in both low-side and high-side current-sensing configurations where high accuracy and low current consumption are required.

7.2 Functional Block Diagram

![Functional Block Diagram of INA190-Q1](image)

1. The ENABLE pin is available only in the DDF package.
7.3 Feature Description

7.3.1 Precision Current Measurement

The INA190-Q1 allows for accurate current measurements over a wide dynamic range. The high accuracy of the device is attributable to the low gain error and offset specifications. The offset voltage of the INA190-Q1 is less than 15 µV. In this case, the low offset improves the accuracy at light loads when \( V_{\text{IN}+} \) approaches \( V_{\text{IN}-} \). Another advantage of low offset is the ability to use a lower-value shunt resistor that reduces the power loss in the current-sense circuit, and improves the power efficiency of the end application.

The maximum gain error of the INA190-Q1 is specified between 0.2% and 0.4% of the actual value, depending on the gain option. As the sensed voltage becomes much larger than the offset voltage, the gain error becomes the dominant source of error in the current-sense measurement. When the device monitors currents near the full-scale output range, the total measurement error approaches the value of the gain error.

7.3.2 Low Input Bias Current

The INA190-Q1 is different from many current-sense amplifiers because this device offers very low input bias current. The low input bias current of the INA190-Q1 has three primary benefits.

The first benefit is the reduction of the current consumed by the device in both the enabled and disabled states. Classical current-sense amplifier topologies typically consume tens of microamps of current at the inputs. For these amplifiers, the input current is the result of the resistor network that sets the gain and additional current to bias the input amplifier. To reduce the bias current to near zero, the INA190-Q1 uses a capacitively coupled amplifier on the input stage, followed by a difference amplifier on the output stage.

The second benefit of low bias current is the ability to use input filters to reject high-frequency noise before the signal is amplified. In a traditional current-sense amplifier, the addition of input filters comes at the cost of reduced accuracy. However, as a result of the low bias currents, input filters have little effect on the measurement accuracy of the INA190-Q1.

The third benefit of low bias current is the ability to use a larger current-sense resistor. This ability allows the device to accurately monitor currents as low as 1 µA.

7.3.3 Low Quiescent Current With Output Enable

The device features low quiescent current (\( I_Q \)), while still providing sufficient small-signal bandwidth to be usable in most applications. The quiescent current of the INA190-Q1 is only 48 µA (typ), while providing a small-signal bandwidth of 35 kHz in a gain of 100. The low \( I_Q \) and good bandwidth allow the device to be used in many portable electronic systems without excessive drain on the battery. Because many applications only need to periodically monitor current, the INA190-Q1 features an enable pin that turns off the device until needed. When in the disabled state, the INA190-Q1 typically draws 10 nA of total supply current.

7.3.4 Bidirectional Current Monitoring

INA190-Q1 devices can sense current flow through a sense resistor in both directions. The bidirectional current-sensing capability is achieved by applying a voltage at the REF pin to offset the output voltage. A positive differential voltage sensed at the inputs results in an output voltage that is greater than the applied reference voltage. Likewise, a negative differential voltage at the inputs results in output voltage that is less than the applied reference voltage. Use Equation 1 to calculate the output voltage of the current-sense amplifier.

\[
V_{\text{OUT}} = (I_{\text{LOAD}} \times R_{\text{SENSE}} \times \text{GAIN}) + V_{\text{REF}}
\]

where

- \( I_{\text{LOAD}} \) is the load current to be monitored.
- \( R_{\text{SENSE}} \) is the current-sense resistor.
- \( \text{GAIN} \) is the gain option of the selected device.
- \( V_{\text{REF}} \) is the voltage applied to the REF pin.
7.3.5 High-Side and Low-Side Current Sensing

The INA190-Q1 supports input common-mode voltages from –0.2 V to +40 V. Because of the internal topology, the common-mode range is not restricted by the power-supply voltage (V_S). The ability to operate with common-mode voltages greater or less than V_S allows the INA190-Q1 to be used in high-side and low-side current-sensing applications (see Figure 7-1).

![Figure 7-1. High-Side and Low-Side Sensing Connections](image)

7.3.6 High Common-Mode Rejection

The INA190-Q1 uses a capacitively coupled amplifier on the front end. Therefore, dc common-mode voltages are blocked from downstream circuits, resulting in very high common-mode rejection. Typically, the common-mode rejection of the INA190-Q1 is approximately 150 dB. The ability to reject changes in the dc common-mode voltage allows the INA190-Q1 to monitor both high- and low-voltage rail currents with very little change in the offset voltage.

7.3.7 Rail-to-Rail Output Swing

The INA190-Q1 allows linear current-sensing operation with the output close to the supply rail and ground. The maximum specified output swing to the positive rail is V_S – 40 mV, and the maximum specified output swing to GND is only GND + 1 mV. The close-to-rail output swing is useful to maximize the usable output range, particularly when operating the device from a 1.8-V supply.
7.4 Device Functional Modes

7.4.1 Normal Operation

The INA190-Q1 is in normal operation when the following conditions are met:

- The power-supply voltage \( V_S \) is between 1.7 V and 5.5 V.
- The common-mode voltage \( V_{CM} \) is within the specified range of \(-0.2 \text{ V to } +40 \text{ V}\).
- The maximum differential input signal times the gain plus \( V_{REF} \) is less than the positive swing voltage \( V_{SP} \).  
- The ENABLE pin is driven or connected to \( V_S \) for package options that feature this pin.
- The minimum differential input signal times the gain plus \( V_{REF} \) is greater than the zero load swing to GND, \( V_{ZL} \) (see the Rail-to-Rail Output Swing section).

During normal operation, this device produces an output voltage that is the \textit{amplified} representation of the difference voltage from \text{IN+} to \text{IN–} plus the voltage applied to the \text{REF} pin.

7.4.2 Unidirectional Mode

This device can be configured to monitor current flowing in one direction (unidirectional) or in both directions (bidirectional) depending on how the \text{REF} pin is connected. Figure 7-2 shows the device operating in unidirectional mode where the output is near ground when no current is flowing. When the current flows from the bus supply to the load, the input voltage from \text{IN+} to \text{IN–} increases and causes the output voltage at the \text{OUT} pin to increase.

![Figure 7-2. Typical Unidirectional Application](image-url)

The linear range of the output stage is limited by how close the output voltage can approach ground under zero input conditions. The zero current output voltage of the INA190-Q1 is very small and for most unidirectional applications the \text{REF} pin is simply grounded. However, if the measured current multiplied by the current sense resistor and device gain is less than the zero current output voltage then bias the \text{REF} pin to a convenient value above the zero current output voltage to get the output into the linear range of the device. To limit common-mode rejection errors, buffer the reference voltage connected to the \text{REF} pin.

A less-frequently used output biasing method is to connect the \text{REF} pin to the power-supply voltage, \( V_S \). This method results in the output voltage saturating at 40 mV less than the supply voltage when no differential input voltage is present. This method is similar to the output saturated low condition with no differential input voltage when the \text{REF} pin is connected to ground. The output voltage in this configuration only responds to currents that develop negative differential input voltage relative to the device \text{IN–} pin. Under these conditions, when the negative differential input signal increases, the output voltage moves downward from the saturated supply voltage. The voltage applied to the \text{REF} pin must not exceed \( V_S \).
Another use for the REF pin in unidirectional operation is to level shift the output voltage. Figure 7-3 shows an application where the device ground is set to a negative voltage so currents biased to negative supplies, as seen in optical networking cards, can be measured. The GND of the INA190-Q1 can be set to negative voltages, as long as the inputs do not violate the common-mode range specification and the voltage difference between vs. and GND does not exceed 5.5 V. In this example, the output of the INA190-Q1 is fed into a positive-biased ADC. By grounding the REF pin, the voltages at the output will be positive and not damage the ADC. To make sure the output voltage never goes negative, the supply sequencing must be the positive supply first, followed by the negative supply.

Figure 7-3. Using the REF Pin to Level-Shift Output Voltage
7.4.3 Bidirectional Mode

The INA190-Q1 devices are bidirectional current-sense amplifiers capable of measuring currents through a resistive shunt in two directions. This bidirectional monitoring is common in applications that include charging and discharging operations where the current flowing through the resistor can change directions.

Figure 7-4. Bidirectional Application

The user can apply a voltage to the REF pin to measure this current flowing in both directions (see Figure 7-4). The voltage applied to REF (V_{REF}) sets the output state that corresponds to the zero-input level state. The output then responds by increasing above V_{REF} for positive differential signals (relative to the IN– pin) and responds by decreasing below V_{REF} for negative differential signals. This reference voltage applied to the REF pin can be set anywhere between 0 V to V_S. For bidirectional applications, V_{REF} is typically set at V_S/2 for equal signal range in both current directions. In some cases, V_{REF} is set at a voltage other than V_S/2; for example, when the bidirectional current and corresponding output signal do not need to be symmetrical.

7.4.4 Input Differential Overload

If the differential input voltage (V_{IN+} – V_{IN–}) times gain exceeds the voltage swing specification, the INA190-Q1 drives its output as close as possible to the positive supply or ground, and does not provide accurate measurement of the differential input voltage. If this input overload occurs during normal circuit operation, then reduce the value of the shunt resistor or use a lower-gain version with the chosen sense resistor to avoid this mode of operation. If a differential overload occurs in a time-limited fault event, then the output of the INA190-Q1 returns to the expected value approximately 80 µs after the fault condition is removed.
7.4.5 Shutdown

Specific package options of the INA190-Q1 feature an active-high ENABLE pin that shuts down the device when pulled to ground. When the device is shut down, the quiescent current is reduced to 10 nA (typical), and the output goes to a high-impedance state. In a battery-powered application, the low quiescent current extends the battery lifetime when the current measurement is not needed. When the ENABLE pin is driven to the supply voltage, the device turns back on. The typical output settling time when enabled is 130 µs.

The output of the INA190-Q1 goes to a high-impedance state when disabled. Therefore, you can connect multiple outputs of the INA190-Q1 together to a single ADC or measurement device (see Figure 7-5).

When connected in this way, enable only one INA190-Q1 at a time, and make sure all devices have the same supply voltage.

![Diagram of INA190-Q1 multiplexing](image)

(1) The ENABLE pin is available only in the DDF package.

Figure 7-5. Multiplexing Multiple Devices With the ENABLE Pin
8 Application and Implementation

**Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI’s customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The INA190-Q1 amplifies the voltage developed across a current-sensing resistor as current flows through the resistor to the load or ground. The high common-mode rejection of the INA190-Q1 make it usable over a wide range of voltage rails while still maintaining an accurate current measurement.

8.1.1 Basic Connections

Figure 8-1 shows the basic connections of the INA190-Q1. Place the device as close as possible to the current sense resistor and connect the input pins (IN+ and IN–) to the current sense resistor through kelvin connections. If present, the ENABLE pin must be controlled externally or connected to VS if not used.

NOTE: To help eliminate ground offset errors between the device and the analog-to-digital converter (ADC), connect the REF pin to the ADC reference input. When driving SAR ADCs, filter or buffer the output of the INA190-Q1 before connecting directly to the ADC.

**Figure 8-1. Basic Connections for the INA190-Q1**
8.1.2 $R_{\text{SENSE}}$ and Device Gain Selection

The accuracy of any current-sense amplifier is maximized by choosing the current-sense resistor to be as large as possible. A large sense resistor maximizes the differential input signal for a given amount of current flow and reduces the error contribution of the offset voltage. However, there are practical limits as to how large the current-sense resistor can be in a given application because of the resistor size and maximum allowable power dissipation. Equation 2 gives the maximum value for the current-sense resistor for a given power dissipation budget:

$$R_{\text{SENSE}} < \frac{P_{\text{D MAX}}}{I_{\text{MAX}}^2}$$  \hspace{1cm} (2)

where:

- $P_{\text{D MAX}}$ is the maximum allowable power dissipation in $R_{\text{SENSE}}$.
- $I_{\text{MAX}}$ is the maximum current that will flow through $R_{\text{SENSE}}$.

An additional limitation on the size of the current-sense resistor and device gain is due to the power-supply voltage, $V_S$, and device swing-to-rail limitations. In order to make sure that the current-sense signal is properly passed to the output, both positive and negative output swing limitations must be examined. Equation 3 provides the maximum values of $R_{\text{SENSE}}$ and $\text{GAIN}$ to keep the device from exceeding the positive swing limitation.

$$I_{\text{MAX}} \times R_{\text{SENSE}} \times \text{GAIN} < V_{\text{SP}} - V_{\text{REF}}$$ \hspace{1cm} (3)

where:

- $I_{\text{MAX}}$ is the maximum current that will flow through $R_{\text{SENSE}}$.
- $\text{GAIN}$ is the gain of the current-sense amplifier.
- $V_{\text{SP}}$ is the positive output swing as specified in the data sheet.
- $V_{\text{REF}}$ is the externally applied voltage on the REF pin.

To avoid positive output swing limitations when selecting the value of $R_{\text{SENSE}}$, there is always a trade-off between the value of the sense resistor and the gain of the device under consideration. If the sense resistor selected for the maximum power dissipation is too large, then it is possible to select a lower-gain device in order to avoid positive swing limitations.

The negative swing limitation places a limit on how small the sense resistor value can be for a given application. Equation 4 provides the limit on the minimum value of the sense resistor.

$$I_{\text{MIN}} \times R_{\text{SENSE}} \times \text{GAIN} > V_{\text{SN}} - V_{\text{REF}}$$ \hspace{1cm} (4)

where:

- $I_{\text{MIN}}$ is the minimum current that will flow through $R_{\text{SENSE}}$.
- $\text{GAIN}$ is the gain of the current-sense amplifier.
- $V_{\text{SN}}$ is the negative output swing of the device (see Rail-to-Rail Output Swing).
- $V_{\text{REF}}$ is the externally applied voltage on the REF pin.

In addition to adjusting $R_{\text{SENSE}}$ and the device gain, the voltage applied to the REF pin can be slightly increased above GND to avoid negative swing limitations.
8.1.3 Signal Conditioning

When performing accurate current measurements in noisy environments, the current-sensing signal is often filtered. The INA190-Q1 features low input bias currents. Therefore, adding a differential mode filter to the input without sacrificing the current-sense accuracy is possible. Filtering at the input is advantageous because this action attenuates differential noise before the signal is amplified. Figure 8-2 provides an example of how to use a filter on the input pins of the device.

![Figure 8-2. Filter at the Input Pins](image)

Figure 8-3 shows the value of $R_{DIFF}$ as a function of the device temperature.

![Figure 8-3. Differential Input Impedance vs. Temperature](image)
As the voltage drop across the sense resistor \( V_{\text{SENSE}} \) increases, the amount of voltage dropped across the input filter resistors \( R_F \) also increases. The increased voltage drop results in additional gain error. Use Equation 5 to calculate the error caused by these resistors.

\[
\text{Error(\%)} = \left( 1 - \frac{R_{\text{DIFF}}}{R_{\text{SENSE}} + R_{\text{DIFF}} + (2 \times R_F)} \right) \times 100
\]

(5)

where:

- \( R_{\text{DIFF}} \) is the differential input impedance.
- \( R_F \) is the added value of the series filter resistance.

The input stage of the INA190-Q1 uses a capacitive feedback amplifier topology in order to achieve high dc precision. As a result, periodic high-frequency shunt voltage (or current) transients of significant amplitude (10 mV or greater) and duration (hundreds of nanoseconds or greater) may be amplified by the INA190-Q1, even though the transients are greater than the device bandwidth. Use a differential input filter in these applications to minimize disturbances at the INA190-Q1 output.

The high input impedance and low bias current of the INA190-Q1 provide flexibility in the input filter design without impacting the accuracy of current measurement. For example, set \( R_F = 100 \, \Omega \) and \( C_F = 22 \, \text{nF} \) to achieve a low-pass filter corner frequency of 36.2 kHz. These filter values significantly attenuate most unwanted high-frequency signals at the input without severely impacting the current sensing bandwidth or precision. If a lower corner frequency is desired, increase the value of \( C_F \).

Filtering the input filters out differential noise across the sense resistor. If high-frequency, common-mode noise is a concern, add an RC filter from the OUT pin to ground. The RC filter helps filter out both differential and common mode noise, as well as, internally generated noise from the device. The value for the resistance of the RC filter is limited by the impedance of the load. Any current drawn by the load manifests as an external voltage drop from the INA190-Q1 OUT pin to the load input. To select the optimal values for the output filter, use Figure 6-33 and see the Closed-Loop Analysis of Load-Induced Amplifier Stability Issues Using ZOUT application report.
8.1.4 Common-Mode Voltage Transients

With a small amount of additional circuitry, the INA190-Q1 can be used in circuits subject to transients that exceed the absolute maximum voltage ratings. The most simple way to protect the inputs from negative transients is to add resistors in series to the IN– and IN+ pins. Use resistors that are 1 kΩ or less, and limit the current in the ESD structures to less than 5 mA. For example, using 1-kΩ resistors in series with the INA190-Q1 allows voltages as low as –5 V, while limiting the ESD current to less than 5 mA. If protection from high-voltage or more-negative, common-voltage transients is needed, use the circuits shown in Figure 8-4 and Figure 8-5. When implementing these circuits, use only Zener diodes or Zener-type transient absorbers (sometimes referred to as transzorbs); any other type of transient absorber has an unacceptable time delay. Start by adding a pair of resistors as a working impedance for the Zener diode (see Figure 8-4). Keep these resistors as small as possible; most often, use around 100 Ω. Larger values can be used with an effect on gain that is discussed in the Signal Conditioning section. This circuit limits only short-term transients; therefore, many applications are satisfied with a 100-Ω resistor along with conventional Zener diodes of the lowest acceptable power rating. This combination uses the least amount of board space. These diodes can be found in packages as small as SOT-523 or SOD-523.

For more information, see the Current Shunt Monitor With Transient Robustness reference design.
8.2 Typical Applications

The low input bias current of the INA190-Q1 allows accurate monitoring of small-value currents. To accurately monitor currents in the microamp range, increase the value of the sense resistor to increase the sense voltage so that the error introduced by the offset voltage is small. Figure 8-6 shows the circuit configuration for monitoring low-value currents. As a result of the differential input impedance of the INA190-Q1, limit the value of \( R_{\text{SENSE}} \) to 1 k\( \Omega \) or less for best accuracy.

![Figure 8-6. Microamp Current Measurement](image)

8.2.1 Design Requirements

Table 8-1 lists the design requirements for the circuit shown in Figure 8-6.

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>EXAMPLE VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Power-supply voltage (( V_S ))</td>
<td>5 V</td>
</tr>
<tr>
<td>Bus supply rail (( V_{\text{CM}} ))</td>
<td>12 V</td>
</tr>
<tr>
<td>Minimum sense current (( I_{\text{MIN}} ))</td>
<td>1 ( \mu )A</td>
</tr>
<tr>
<td>Maximum sense current (( I_{\text{MAX}} ))</td>
<td>150 ( \mu )A</td>
</tr>
<tr>
<td>Device gain (( \text{GAIN} ))</td>
<td>25 V/V</td>
</tr>
<tr>
<td>Reference voltage (( V_{\text{REF}} ))</td>
<td>0 V</td>
</tr>
</tbody>
</table>
8.2.2 Detailed Design Procedure

The maximum value of the current-sense resistor is calculated based on choice of gain, value of the maximum current to be sensed \( (I_{\text{MAX}}) \), and the power supply voltage \( (V_S) \). When operating at the maximum current, the output voltage must not exceed the positive output swing specification, \( V_{SP} \). For the given design parameters, Equation 6 determines that the maximum value for \( R_{\text{SENSE}} \) is 1.321 kΩ.

\[
R_{\text{SENSE}} < \frac{V_{SP}}{I_{\text{MAX}} \times \text{GAIN}}
\]

However, because this value exceeds the maximum recommended value for \( R_{\text{SENSE}} \), a resistance value of 1 kΩ must be used. When operating at the minimum current value, \( I_{\text{MIN}} \) the output voltage must be greater than the swing to GND \( (V_{SN}) \), specification. For this example, Equation 7 determines that the output voltage at the minimum current is 25 mV, which is greater than the value for \( V_{SN} \).

\[
V_{\text{OUTMIN}} = I_{\text{MIN}} \times R_{\text{SENSE}} \times \text{GAIN}
\]

8.2.3 Application Curve

Figure 8-7 shows the output of the device under the conditions given in Table 8-1 and with \( R_{\text{SENSE}} = 1 \text{ kΩ} \).

9 Power Supply Recommendations

The input circuitry of the INA190-Q1 accurately measures beyond the power-supply voltage, \( V_S \). For example, \( V_S \) can be 5 V, whereas the bus supply voltage at IN+ and IN– can be as high as 40 V. However, the output voltage range of the OUT pin is limited by the voltage on the VS pin. The INA190-Q1 also withstands the full differential input signal range up to 40 V at the IN+ and IN– input pins, regardless of whether the device has power applied at the VS pin. There is no sequencing requirement for \( V_S \) and \( V_{\text{IN+}} \) or \( V_{\text{IN–}} \).
10 Layout

10.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a Kelvin or 4-wire connection. This connection technique makes sure that only the current-sensing resistor impedance is detected between the input pins. Poor routing of the current-sensing resistor commonly results in additional resistance present between the input pins. Given the very low ohmic value of the current resistor, any additional high-current carrying impedance can cause significant measurement errors.

- Place the power-supply bypass capacitor as close as possible to the device power supply and ground pins. The recommended value of this bypass capacitor is 0.1 µF. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

- When routing the connections from the current-sense resistor to the device, keep the trace lengths as short as possible. The input filter capacitor $C_F$ should be placed as close as possible to the input pins of the device.

10.2 Layout Examples

![Recommended Layout for SC70 (DCK) Package](image-url)

**Figure 10-1. Recommended Layout for SC70 (DCK) Package**
Figure 10-2. Recommended Layout for SOT23-8 (DDF) Package
11 Device and Documentation Support
11.1 Documentation Support
11.1.1 Related Documentation
For related documentation see the following: Texas Instruments, *INA190EVM user's guide*

11.2 Receiving Notification of Documentation Updates
To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Support Resources
*TI E2E™ support forums* are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's *Terms of Use*.

11.4 Trademarks
*TI E2E™* is a trademark of Texas Instruments. All trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution
This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 Glossary
*TI Glossary* This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.
## PACKAGING INFORMATION

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<tr>
<th>Orderable Device</th>
<th>Status (1)</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan (2)</th>
<th>Lead finish/ Ball material (6)</th>
<th>MSL Peak Temp (3)</th>
<th>Op Temp (°C)</th>
<th>Device Marking (4/5)</th>
<th>Samples</th>
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(1) The marketing status values are defined as follows:
- **ACTIVE:** Product device recommended for new designs.
- **LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
- **NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
- **PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.
- **OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
- **RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
- **Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) **MSL, Peak Temp. -** The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a “~” will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF INA190-Q1:
- Catalog : INA190

NOTE: Qualified Version Definitions:
- Catalog - TI's standard catalog product
## TAPE AND REEL INFORMATION

### REEL DIMENSIONS
- **Reel Diameter**
- **Reel Width (W1)**

### TAPE DIMENSIONS
- **A0**: Dimension designed to accommodate the component width
- **B0**: Dimension designed to accommodate the component length
- **K0**: Dimension designed to accommodate the component thickness
- **W**: Overall width of the carrier tape
- **P1**: Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

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<th>Package Drawing</th>
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<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P1 (mm)</th>
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*All dimensions are nominal*
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<th>Pins</th>
<th>SPQ</th>
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<th>Width (mm)</th>
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*All dimensions are nominal*
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

2. This drawing is subject to change without notice.

3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

7. Board assembly site may have different recommendations for stencil design.
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Falls within JEDEC MO-203 variation AB.
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC-7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
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